## SURFACE MOUNT-CERAMIC **ATTENUATOR, PIN DIODE** 0.8-4 GHz

#### **GENERAL INFORMATION**

The PI-800 Se ies atten uators are part of the rew Surfpac product line featuring good inter modulation peformance compared to their GaAs counter parts for PCS/cellular base station use. In addition, the PIN diodes off er good po wer-handling capabilities and are less sensitive to electrostatic discharge pto lems. These features are important consider ations in base station applications where the effects of antennarelated RFs witching and indirect lightning-induced/ oltage splix es are present.

PIN diode components and ve inherent advantages over the GaAs altenatives at PCS/cellular frequencies. The PI-800 Se ies attenuator makes use of these advantages in a dv w cost sufface-mount package suitable for pick-and-place applications. As a result, the attentuator satisfies both the technical specifications and the manufacturing requirements of tod y's demanding commercial maketplace.

PIN diodes are widely accepted as more robust alter natives to GaAs FETs and of er higher isolation with b wer insertion loss than plastic packaged GaAs attree uators at P ersonal Communications Service (PCS) frequencies. The PI-800 Se ies analog attree uator incorporates PIN diodes with highly reliable thick-film technology and suff ace mount components on a miniatureol w cost sealed stir ace mount alumina header. This new attenuator provides a good match, flat attree uation and overall superior performance over the 0.8–4 GHz frequency range, and can be optimzi edo ver lower frequencyr anges.

#### **GENERAL SPECIFICATIONS**

Frequency Range:	10% B .W. Typical, 0.8–4 GHz		
Insertion Loss:	Per chart		
Attenuation Range:	Per chart		
Control Voltage:	0-5 VDC		
1 dB Compression Point:	+27 dBm		
Construction:	Thick film alumina with epo xy sealed		
	cover		
Speed:	2 µsec		
Temperature:	<ul> <li>-10 to +80°C. See application note for recommended maximum reflow soldering temperatures.</li> </ul>		

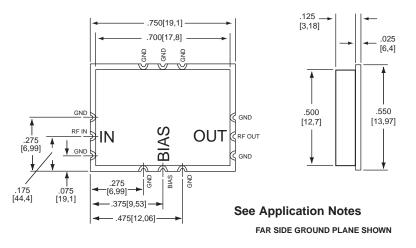


### FEATURES

- Low Loss
- Low I.M. products
- PIN diode performance
- Low VSWR
- 500 mw power
- · Pick and place and reflow manufacture
- Shunt diode design

	Insertion					
	Frequency	Attenuation	Loss (dB)	VSWR	Typical	
Model	(GHz)	Range (dB)	Maximum	Maximum	Current(mA)	
PI-820NS	1.84-1.94	0-6	0.7	1.50	30	
PI-840	0.8-1.0	0-35	0.5	1.40	50	
PI-850	0.8-1.0	0-30	1.0	1.50	50	
PI-845	1.7-2.0	0-35	0.8	1.50	50	
PI-855	1.7-2.0	0-25	1.0	1.50	50	
PI-A05	2.4-2.46	0-20	1.3	1.50	50	
PI-A04	3.55-3.65	0-25	1.5	1.50	50	
PI-A06	3.5-4.0	0-20	1.5	1.50	50	

#### **OUTLINE-PI-800 SERIES**



KEY: Inches[Millimeters] .XX ±.03 .XXX ±.010 [.X ±0.8 .XX ±0.25]



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# **SERIES PI-800**